

New Jersey Semi-Conductor Products, Inc.

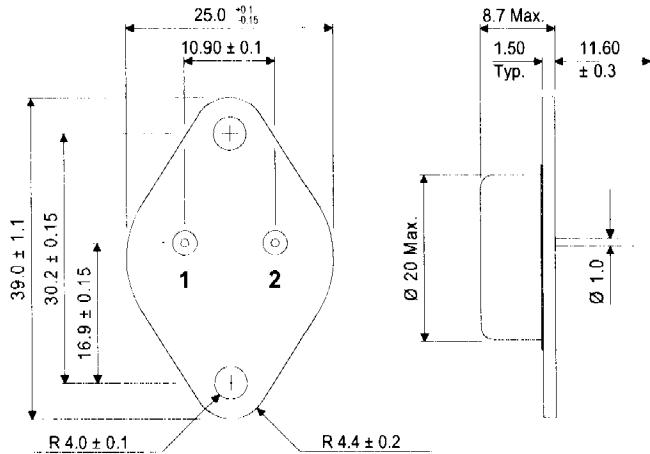
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BUZ900
BUZ901

MECHANICAL DATA

Dimensions in mm



TO-3
Pin 1 – Gate Pin 2 – Drain Case – Source

N-CHANNEL POWER MOSFET

POWER MOSFETS FOR AUDIO APPLICATIONS

FEATURES

- HIGH SPEED SWITCHING
- N-CHANNEL POWER MOSFET
- SEMEFAB DESIGNED AND DIFFUSED
- HIGH VOLTAGE (160V & 200V)
- HIGH ENERGY RATING
- ENHANCEMENT MODE
- INTEGRAL PROTECTION DIODE
- P-CHANNEL ALSO AVAILABLE AS
BUZ905 & BUZ906

ABSOLUTE MAXIMUM RATINGS

($T_{case} = 25^\circ C$ unless otherwise stated)

		BUZ900	BUZ901
V_{DSX}	Drain – Source Voltage	160V	200V
V_{GSS}	Gate – Source Voltage	$\pm 14V$	
I_D	Continuous Drain Current	8A	
$I_{D(PK)}$	Body Drain Diode	8A	
P_D	Total Power Dissipation @ $T_{case} = 25^\circ C$	125W	
T_{stg}	Storage Temperature Range	–55 to 150°C	
T_j	Maximum Operating Junction Temperature	150°C	
$R_{\theta JC}$	Thermal Resistance Junction – Case	1°C/W	

BUZ900 BUZ901

STATIC CHARACTERISTICS ($T_{case} = 25^\circ C$ unless otherwise stated)

Characteristic	Test Conditions		Min.	Typ.	Max.	Unit
BV_{DSX} Drain – Source Breakdown Voltage	$V_{GS} = -10V$	BUZ900	160			V
	$I_D = 10mA$	BUZ901	200			
BV_{GSS} Gate – Source Breakdown Voltage	$V_{DS} = 0$	$I_G = \pm 100\mu A$	± 14			V
$V_{GS(OFF)}$ Gate – Source Cut-Off Voltage	$V_{DS} = 10V$	$I_D = 100mA$	0.15		1.5	V
$V_{DS(SAT)}^*$ Drain – Source Saturation Voltage	$V_{GD} = 0$	$I_D = 8A$			12	V
		$V_{DS} = 160V$			10	
I_{DSX} Drain – Source Cut-Off Current	$V_{GS} = -10V$	BUZ900			10	mA
		$V_{DS} = 200V$				
		BUZ901				
yfs^* Forward Transfer Admittance	$V_{DS} = 10V$	$I_D = 3A$	0.7		2	S

DYNAMIC CHARACTERISTICS ($T_{case} = 25^\circ C$ unless otherwise stated)

Characteristic	Test Conditions		Min.	Typ.	Max.	Unit
C_{iss} Input Capacitance	$V_{DS} = 10V$			500		
C_{oss} Output Capacitance	$f = 1MHz$			300		pF
C_{rss} Reverse Transfer Capacitance				10		
t_{on} Turn-on Time	$V_{DS} = 20V$			100		ns
t_{off} Turn-off Time	$I_D = 5A$			50		

* Pulse Test: Pulse Width = $300\mu s$, Duty Cycle $\leq 2\%$.

